3-TERMINAL 1A NEGATIVE VOLTAGE REGULATORS

The MC79XX series of three-terminal negative regulators are available in TO-220 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut-down and safe area protection, making it essentially indestructible.

TO-220 1: GND 2: Input 3: Output

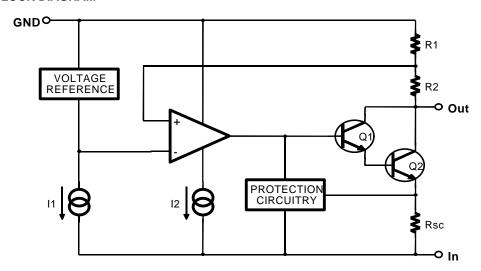
FEATURES

- . Output Current in Excess of 1A
- Output Voltages of -5, -6, -8, -12, -15, -18, -24V
- Internal Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe-Area Compensation

ORDERING INFORMATION

Device	Output Voltage Tolerance	Package	Operating Temperature
MC79XXCT (LM79XXCT) (KA79XX)	± 4%		
KA79XXA	± 2%	TO-220	0 ~+125°C

BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS (T_A=+25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
Input Voltage	Vı	-35	V
Thermal Resistance Junction-Cases Junction-Air	$R_{ heta JC} \ R_{ heta JA}$	5 65	°C / W
Operating Temperature Range	T _{OPR}	0 ~ +125	°C
Storage Temperature Range	T _{STG}	- 65 ~ +150	°C

LM7905 ELECTRICAL CHARACTERISTICS

 $(V_{I}=10V,\,I_{O}=500mA,\,0^{\circ}C\leq T_{J}\leq +125^{\circ}C,\,C_{I}=2.2\mu F,\,C_{O}=1\mu F,\,unless\,otherwise\,specified.)$

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+25°C	- 4.8	- 5.0	- 5.2	
Output Voltage	Vo	$I_0 = 5mA \text{ to } 1A, P_0 15W$ $V_1 = -7 \text{ to } -20V$	- 4.75	-5.0	- 5.25	V
		$V_{i} = -7 \text{ to } -20V$ $I_{0}=1A$		5	50	mV
Line Regulation	ΔVο	$T_J = 25^{\circ}C$ $\frac{I_0 = 1A}{V_1 = -8 \text{ to } -12V}$ $I_0 = 1A$		2	25	
Line Regulation	0	V _I = -7.5 to -25V		7	50	
		V_{i} = -8 to -12V I_{O} =1A		7	50	
		I _O = 5mA to 1.5A		10	100	
Load Regulation	ΔV_{O}	$T_J = +25^{\circ}C$ $I_O = 250 \text{ to } 750\text{mA}$		3	50	mV
Quiescent Current	ΙQ	T _J =+25°C		3	6	mA
Quiescent Current Change	ΔI_{O}	$I_0 = 5 \text{mA to } 1 \text{A}$		0.05	0.5	mA
Quiocociii Guiroiii Giiarigo	~	$V_1 = -8 \text{ to } -25 \text{V}$		0.1	0.8	1117 (
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_O = 5mA$		- 0.4		mV/°C
Output Noise Voltage	V _N	f = 10Hz to $100KHzT_A = +25^{\circ}C$		40		μV
Ripple Rejection	RR	$f = 120Hz, I_0 = -35V$ $\Delta V_1 = 10V$	54	60		dB
Dropout Voltage	V _D	T _J =+25°C I _O = 1A		2		V
Short Circuit Current	I _{sc}	$T_J = +25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+25°C		2.2		Α

^{*} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7906 ELECTRICAL CHARACTERISTICS

 $(V_1 = 11V, I_0 = 500mA, 0^{\circ}C \le T_J \le +125^{\circ}C, C_1 = 2.2\mu F, C_0 = 1\mu F$, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J = +25°C	- 5.75	- 6	- 6.25	
Output Voltage	Vo	$I_O = 5 \text{mA to 1A, P}_O$ 15W $V_I = -9 \text{ to - 21V}$	- 5.7	- 6	- 6.3	V
Line Regulation	ΔVo	$T_J = 25^{\circ}C$ $V_I = -8 \text{ to } -25V$ $V_I = -9 \text{ to } -12V$		10	120	mV
Line Regulation	Δνο	V_{i} = - 9 to -12V		5	60	IIIV
1. 15. 15		$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		10	120	.,
Load Regulation	ΔV _O	T _J =+ 25°C I _O = 250 to 750mA		3	60	mV
Quiescent Current	IQ	T _J =+ 25°C		3	6	mA
Outpount Current Change	ΔI_Q	I _O = 5mA to 1A			0.5	Л
Quiescent Current Change	ΔiQ	V _I = -9 to -25V			1.3	mA
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	I _O = 5mA		-0.5		mV/°C
Output Noise Voltage	V _N	f = 10Hz to $100KHzT_A = + 25°C$		130		μV
Ripple Rejection	RR	$f = 120Hz$ $\Delta V_I = 10V$	54	60		dB
Dropout Voltage	V _D	T _J =+ 25°C I _O = 1A		2		٧
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V		300		mA
Peak Current	I _{PK}	T _{.j} = +25°C		2.2		Α

 $^{^*}$ Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7908 ELECTRICAL CHARACTERISTICS

 $(V_1 = 14V, I_0 = 500 mA, 0^{\circ}C \le T_J \le +125^{\circ}C, C_1 = 2.2 \mu F, C_0 = 1 \mu F, unless otherwise specified.)$

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+ 25°C	- 7.7	- 8	- 8.3	
Output Voltage	Vo	$I_O = 5 \text{mA to 1A}, P_O = 15 \text{W}$ $V_I = -1.5 \text{ to } -23 \text{V}$	- 7.6	- 8	- 8.4	V
Line Regulation	ΔV_{O}	$V_{I} = -10.5 \text{ to } -25 \text{V}$		10	100	mV
Line Regulation	Δνο	$T_J = 25^{\circ}C$ $\frac{V_i = -10.5 \text{ to } -25V}{V_i = -11 \text{ to } -17V}$		5	80	IIIV
Load Regulation		$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		12	160	.,,
	ΔVo	T _J =+ 25°C I _O = 250 to 750mA		4	80	mV
Quiescent Current	ΙQ	T _J =+ 25°C		3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to 1A		0.05	0.5	mA
Quiescent Current Change	ΔiQ	$V_1 = -11.5 \text{ to } -25 \text{V}$		0.1	1	IIIA
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$		-0.6		mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100KHz T _A =+ 25°C		175		μV
Ripple Rejection	RR	$f = 120Hz$ $\Delta V_1 = 10V$	54	60		dB
Dropout Voltage	V_D	T _J =+ 25°C I _O = 1A		2		V
Short Circuit Current	I _{sc}	T _J =+ 25°C, V _I = -35V		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^{\}star}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7909 ELECTRICAL CHARACTERISTICS

(V_I = 14V, I_O = 500mA, 0° C \leq T_J \leq + 125 $^{\circ}$ C, C_I =2.2 μ F, C_O = 1 μ F, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+ 25°C	- 8.7	- 9.0	- 9.3	
Output Voltage	Vo	$I_O = 5mA$ to 1A, P_O 15W $V_I = -1.5$ to -23V	- 8.6	- 9.0	- 9.4	V
Line Regulation	ΔV_{O}	$V_1 = -10.5 \text{ to } -25 \text{ V}$		10	180	\/
Line Regulation	Δνο	$T_J = 25^{\circ}C$ $V_i = -10.5 \text{ to } -25V$ $V_i = -11 \text{ to } -17V$		5	90	mV
Load Regulation		$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		12	180	\/
	ΔV _O	T _J =+ 25°C I _O = 250 to 750mA		4	90	mV
Quiescent Current	ΙQ	T _J =+ 25°C		3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to 1A		0.05	0.5	mA
Quescent ourient onlange	ΔiQ	$V_I = -11.5 \text{ to } -25 \text{V}$		0.1	1	ША
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$		-0.6		mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100KHz T _A =+ 25°C		175		μV
Ripple Rejection	RR	f = 120Hz $\Delta V_i = 10V$	54	60		dB
Dropout Voltage	V _D	T _J =+ 25°C I _O = 1A		2		V
Short Circuit Current	I _{sc}	$T_J = +25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+25°C		2.2		Α

 $^{^*}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7912 ELECTRICAL CHARACTERISTICS

(V_I= 18V, I_O =500mA, 0° C \leq T_J \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O = 1 μ F, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J = +25°C	-11.5	-12	-12.5	
Output Voltage	Vo	$I_0 = 5\text{mA to 1A}, P_0 = 15W$ $V_1 = -15.5 \text{ to } -27V$	-11.4	-12	-12.6	V
Line Regulation	ΔVo	$T_J = 25^{\circ}C$ $V_I = -14.5 \text{ to } -30V$ $V_I = -16 \text{ to } -22V$		12	240	mV
Line Regulation	400	V_{i} = -16 to -22V		6	120	1110
Load Regulation		$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		12	240	.,
	ΔV _O	$T_J = + 25^{\circ}C$ $I_O = 250 \text{ to } 750\text{mA}$		4	120	mV
Quiescent Current	ΙQ	T _J =+ 25°C		3	6	mA
Ouisesent Current Change	ΔI_{O}	$I_O = 5 \text{mA to } 1 \text{A}$		0.05	0.5	mA
Quiescent Current Change	ΔIQ	$V_1 = -15 \text{ to } -30 \text{V}$		0.1	1	IIIA
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_O = 5mA$		-0.8		mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100KHz T _A =+ 25°C		200		μV
Ripple Rejection	RR	f = 120Hz $\Delta V_1 = 10V$	54	60		dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A		2		V
Short Circuit Current	I _{SC}	$T_J = + 25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^{\}star}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7915 ELECTRICAL CHARACTERISTICS

(V_I = 23V, I_O = 500mA, $0^{\circ}C \le T_{J}$ +125°C, C_{I} =2.2 μ F, C_{O} = 1 μ F, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+ 25°C	-14.4	-15	-15.6	
Output Voltage	Vo	$I_O = 5mA \text{ to } 1A, P_O 15W$ V _I = -18 to -30V	-14.25	-15	-15.75	V
Line Regulation	ΔV_{O}	$T_{J} = 25^{\circ}C$ $V_{I} = -17.5 \text{ to } -30V$		12	300	mV
Line Regulation	Δν0	V_{i} = -20 to -26V		6	150	IIIV
Load Regulation	41/	$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		12	300	ma\/
	ΔV_{O}	T _J =+ 25°C I _O = 250 to 750mA		4	150	mV
Quiescent Current	lα	T _J =+ 25°C		3	6	mA
Quiescent Current Change	AI-	$I_O = 5mA$ to 1A		0.05	0.5	mA
Quiescent Current Change	ΔI_Q	$V_1 = -18.5 \text{ to } -30 \text{V}$		0.1	1	1117 (
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$		-0.9		mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100Khz T _A =+ 25°C		250		μV
Ripple Rejection	RR	f = 120Hz $\Delta V_1 = 10V$	54	60		dB
Dropout Voltage	V_D	T _J =+25°C I _O = 1A		2		V
Short Circuit Current	I _{SC}	$T_J = + 25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^*}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7918 ELECTRICAL CHARACTERISTICS

(V_I = 27V, I_O = 500mA, 0° C \leq T_J \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O = 1 μ F, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+ 25°C	-17.3	-18	-18.7	
Output Voltage	Vo	$I_O = 5mA \text{ to } 1A, P_O 15W$ V ₁ = -22.5 to -33V	-17.1	-18	-18.9	V
Line Regulation	ΔVo	$T_{ij} = 25^{\circ}C$ $V_{ij} = -21 \text{ to } -33V$		15	360	mV
Line regulation	400	V_{i} = -24 to -30V		8	180	IIIV
Load Regulation		$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		15	360	
	ΔVo	T _J =+ 25°C I _O = 250 to 750mA		5	180	mV
Quiescent Current	lα	T _J =+ 25°C		3	6	mA
Ouisesent Current Change	4.1	$I_O = 5mA$ to 1A			0.5	mA
Quiescent Current Change	ΔI_Q	$V_1 = -22 \text{ to } -33 \text{V}$			1	IIIA
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$		-1		mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100KHz T _A =+ 25°C		300		μV
Ripple Rejection	RR	$f = 120Hz$ $\Delta V_{I} = 10V$	54	60		dB
Dropout Voltage	V _D	T _J =+ 25°C I _O = 1A		2		V
Short Circuit Current	I _{sc}	$T_J = + 25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^*}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7924 ELECTRICAL CHARACTERISTICS

(V_I = 33V, I_O = 500mA, 0° C \leq T_J \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O = 1 μ F, unless otherwise specified.)

Characteristic	Symbol	Test Conditions		Min	Тур	Max	Unit
		T _J =+25°C		- 23	- 24	- 25	
Output Voltage	Vo	_	$I_0 = 5\text{mA to 1A}, P_0 \le 15\text{W}$ $V_1 = -27 \text{ to } -38\text{V}$		- 24	- 25.2	V
Line Regulation	ΔV_{Ω}	T _{.1} = 25°C	$V_I = -27 \text{ to } -38 \text{V}$		15	480	mV
Line Regulation	Δνο	1j = 25 C	V_{I} = - 30 to - 36V		8	180	111 V
Lord Domission		$T_J = +25^{\circ}C$ $I_O = 5mA$ to	1.5A		15	480	
Load Regulation	ΔV _O	$T_J = + 25^{\circ}C$ $I_O = 250 \text{ to } 7$	750mA		5	240	mV
Quiescent Current	ΙQ	T _J =+ 25°C			3	6	mA
Ouisseent Current Change	ΔI_{Q}	$I_O = 5mA$ to 1A				0.5	mA
Quiescent Current Change	ΔiQ	$V_1 = -27 \text{ to } -38V$				1	IIIA
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$			-1		mV/°C
Output Noise Voltage	V _N	$f = 10Hz$ to $T_A = +25$ °C	100KHz		400		μV
Ripple Rejection	RR	f = 120Hz $\Delta V_1 = 10V$		54	60		dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A			2		V
Short Circuit Current	I _{sc}	T _{.1} =+ 25°C, V ₁ = -35V			300		mA
Peak Current	I _{PK}	T _J =+25°C	•		2.2		Α

 $^{^{\}star}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7905A ELECTRICAL CHARACTERISTICS

(V_I = 10V, I_O = 500mA, 0° C \leq T_J \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O =1 μ F, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+ 25°C	- 4.9	- 5.0	- 5.1	
Output Voltage	Vo	$I_0 = 5mA \text{ to } 1A, P_0 15W$ $V_1 = -7 \text{ to } -20V$	- 4.8	-5.0	- 5.2	V
		$V_{I} = -7 \text{ to } -20V$ $I_{O} = 1A$		5	50	mV
Line Regulation	ΔV_{O}	$T_J = +25^{\circ}C$ $\frac{I_0=1A}{V_1 = -8 \text{ to -12V}}$ $I_0=1A$		2	25	
Line Regulation		$V_1 = -7.5 \text{ to } -25 \text{V}$		7	50	
		V _I = -8 to -12V I _O =1A		7	50	
		$I_O = 5$ mA to 1.5A		10	100	
Load Regulation	ΔV_{O}	$T_J = + 25^{\circ}C$ $I_O = 250 \text{ to } 750\text{mA}$		3	50	mV
Quiescent Current	lα	T _J = +25°C		3	6	mA
Quiescent Current Change	ΔI_{O}	I _O = 5mA to 1A		0.05	0.5	mA
Quiescent Ourrent Onlange	Q	$V_1 = -8 \text{ to } -25 \text{V}$		0.1	0.8	IIIA
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$		- 0.4		mV/°C
Output Noise Voltage	V _N	f = 10Hz to $100KHzT_A = + 25°C$		40		μV
Ripple Rejection	RR	$f = 120Hz, I_0 = -35V$ $\Delta V_1 = 10V$	54	60		dB
Dropout Voltage	V _D	$T_J = + 25^{\circ}C$ $I_O = 1A$		2		V
Short Circuit Current	I _{SC}	T _J =+ 25°C, V _I = -35V		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^*}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7912A ELECTRICAL CHARACTERISTICS

(V_I= 18V, I_O =500mA, 0° C \leq T_J \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O = 1 μ F, unless otherwise specified.)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J =+ 25°C	-11.75	-12	-12.25	
Output Voltage	Vo	$I_O = 5mA \text{ to } 1A, P_O 15W$ $V_I = -15.5 \text{ to } -27V$	-11.5	-12	-12.5	V
Line Regulation	ΔV_{O}	$T_J = +25^{\circ}C$ $V_i = -14.5 \text{ to } -30V$		12	240	mV
Line Regulation	Δν0	V_{i} = -16 to -22V		6	120	IIIV
15 15		$T_J = +25^{\circ}C$ $I_O = 5mA$ to 1.5A		12	240	.,
Load Regulation	ΔV _O	$T_J = + 25^{\circ}C$ $I_O = 250 \text{ to } 750\text{mA}$		4	120	mV
Quiescent Current	ΙQ	T _J =+ 25°C		3	6	mA
Quiescent Current Change	ΔI	$I_O = 5mA$ to 1A		0.05	0.5	mA
Quiescent Current Change	ΔI_Q	$V_{I} = -15 \text{ to } -30 \text{V}$		0.1	1	IIIA
Temperature Coefficient of V _D	$\Delta V_O/\Delta T$	$I_O = 5mA$		-0.8		mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100 Khz $T_A = + 25$ °C		200		μV
Ripple Rejection	RR	$f = 120Hz$ $\Delta V_I = 10V$	54	60		dB
Dropout Voltage	V _D	T _J =+ 25°C I _O = 1A		2		V
Short Circuit Current	I _{SC}	$T_J = + 25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^{\}star}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



LM7915A ELECTRICAL CHARACTERISTICS

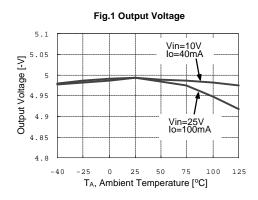
(V_I = 23V, I_O = 500mA, 0° C \leq T_J \leq +125 $^{\circ}$ C, C_I =2.2 μ F, C_O = 1 μ F, unless otherwise specified.)

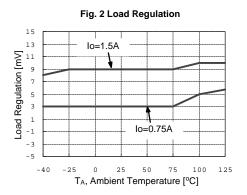
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
		T _J = +25°C	-14.7	-15	-15.3	
Output Voltage	Vo	$I_O = 5mA \text{ to } 1A, P_O 15W$ $V_I = -18 \text{ to } -30V$		-15	-15.6	V
Line Regulation	ΔV_{O}	$T_{J} = +25^{\circ}C$ $V_{I} = -17.5 \text{ to } -30V$		12 300		mV
		V_{i} = -20 to -26V		6	150	IIIV
Load Regulation		$T_J = + 25^{\circ}C$ $I_O = 5mA \text{ to } 1.5A$		12	300 mV	
	ΔV _O	T _J =+ 25°C I _O = 250 to 750mA		4	150	mv
Quiescent Current	lα	T _J =+ 25°C		3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to 1A		0.05 0.5 m/A		mA
		$V_1 = -18.5 \text{ to } -30 \text{V}$		0.1	1	
Temperature Coefficient of V _D	$\Delta V_{O}/\Delta T$	$I_0 = 5mA$		-0.9		mV/°C
Output Noise Voltage	V_N	f = 10Hz to $100KHzT_A = +25°C$		250		μV
Ripple Rejection	RR	$f = 120Hz$ $\Delta V_1 = 10V$	54	60		dB
Dropout Voltage	V_D	T _J = +25°C I _O = 1A		2		V
Short Circuit Current	I _{SC}	$T_J = + 25^{\circ}C, V_I = -35V$		300		mA
Peak Current	I _{PK}	T _J =+ 25°C		2.2		Α

 $^{^*}$ Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.



TYPICAL PERFORMANCE CHARACTERISTICS





5
4.5
4.5
3
3.5
3
7
2.5
1.5
0.5

Fig.3 Quiescent Current

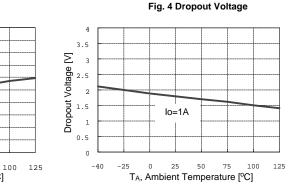
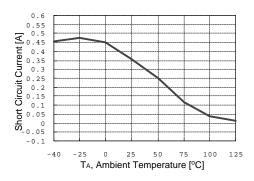


Fig.5 Short Circuit Current

25 0 25 50 75 T_A, Ambient Temperature [°C]

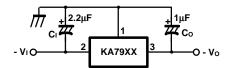
-40





TYPICAL APPLICATIONS

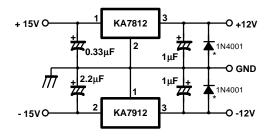
Fig. 6 Negative Fixed output regulator



Notes:

- To specify an output voltage, substitute voltage value for "XX " (1)
- Required for stability. For value given, capacitor must be solid tantalum. If aluminum electronics are used, at least ten times value shown should be selected. Ct. is required if regulator is located an approach to appreciable
- distance from power supply filter.
- To improve transient response. If large capacitors are used, a high current diode from input to output (1N400l or similar) should be introduced to protect the device from momentary input short circuit.

Fig. 7 Split power supply (±12V/1A)



^{*:} Against potential latch-up problems.



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